

designed and manufactured in Germany

Data Sheet IVS-162

Version 4.2 - 21.05.2014

PRODUCT FAMILY

K-Band VCO Transceiver

Door Opener

Industrial Applications

APPLICATIONS



FEATURES:

- » VCO-Transceiver centered @ 24GHz
- » FMCW/FSK capable; therefore measurement of distance as well as recognition of stationary objects possible (depending on modulation)
- » split transmit and receive path for maximum gain
- » stereo (dual channel) operation for direction of motion indection
- » IF-pre-amplifier, bandwith limited for lowest noise performance
- » compact outline dimensions



DESCRIPTION

The IVS-162 is the FMCW/FSK-version of the IPS-154. The same outline dimensions as well as the identical antenna pattern make this product perfect for upgrading existing systems

CERTIFICATES

InnoSenT GmbH has established and applies a quality system for: development, production and sales of radar sensors for industrial and automotive sensors.



ADDITIONAL INFORMATION

InnoSenT Standard Product. Changes will not be notified as long as there is no influence on form, fit and within this datasheet specified function of the product.

RoHS-INFO

This product is compliant to the restriction of hazardous substances (RoHS - European Union directive 2011/65/EU).

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ELECTRICAL CHARACTERISTICS

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Transmitter						
transmit frequencies	depending on V_{tune}	f	24.000 - 24.250			GHz
freq @V _{tune} 5,0V	@ 25°C	f _{5,0V}	24.100	24.125	24.150	GHz
varactor tuning voltage		V _{tune}	0.5		10	V
varactor tuning impedance				10k		Ω
modulation input					150	kHz
tuning slope				40		MHz/V
temperature drift (frequency)		∆f		-1		MHz/°C
output power (EIRP)	@ 25°C	P _{out}		15		dBm
Receiver						
I/Q balance		amplitude		0	6	dB
		phase	60	90	120	0
IF-output		voltage offset	1.0	2.2	4.0	V
IF - amplifier		bandwidth		DC - 50		kHz
		gain		20		dB
Antenna System Pattern (com	pare with antenna plot on page 3)					
full beam width @ -3dB	azimuth	horizontal		45		0
	elevation	vertical		38		0
side-lobe suppression	azimuth	horizontal		15		dB
	elevation	vertical		20		dB
Power supply						
supply voltage		V _{cc}	4.75	5.00	5.25	V
supply current	IF-amp included	I _{cc}		35	50	mA
Environment						
operating temperature		T _{op}	-20		+60	°C
storage temperature		T _{stg}	-40		+85	°C
Mechanical Outlines						
outline dimensions	compare drawing	height length width		8.3 (19) 44.0 30.0		mm

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TX- ANTENNA PATTERN

Antenna Orientation:





PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
full beam width @ -3dB		horizontal		45		0
		vertical		38		o
side-lobe suppression		horizontal		15		dB
		vertical		20		dB

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INTERFACE

The sensor provides a 2.54mm grid, single row pin header (square pin □ 0.635mm).

PIN #	DESCRIPTION	IN/OUT	COMMENT
1	V _{tune}	input	varactor tuning voltage
2	enable	input	active low
3	V _{cc}	input	supply voltage (+5 V)
4	GND	input	analog ground
5	IF1	output	signal I(nphase)
6	IF2	output	signal Q(uadrature)
7	GND	input	analog ground
8	GND	input	analog ground
9	NC		not connected
10	NC		not connected

MECHANICAL OUTLINES



top view

side view

bottom view

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ESD-INFORMATION



This InnoSenT sensor is sensitive to damage from ESD. Normal precautions as usually applied to CMOS devices are sufficient when handling the device. Touching the signal output pins has to be avoided at any time before soldering or plugging the device into a motherboard.

APPROVAL

This Data Sheet contains the technical specifications of the described product. All previous versions of this Data Sheet are no longer valid.

The sensor uses Hydrocarbon based material which may change its dielectric properties when used in an oxidative environment. This may vary based on temperature. Therefore InnoSenT recommends evaluating this influence within the specific environment.

VERSION	DATE	COMMENT
4.1	18.04.2013	new layout
4.2	21.05.2014	antenna orientation, produkt picture, ESD-information ; RoHS(1) to RoHS(2)

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